NSN 5961-01-215-1554

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-215-1554

Inclosure Material:

Metal

Overall Length:

1.550 inches

Overall Height:

0.300 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage, dc and 80.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, dc

Current Rating Per Characteristic:

25.00 amperes source cutoff current and 10.00 amperes source cutoff current

Power Rating Per Characteristic:

200.0 watts small-signal input power, common-collector absolute

Transfer Ratio:

80.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0